



16-Ch/Dual 8-Ch High-Performance CMOS Analog Multiplexers

DESCRIPTION

The DG406B is a 16-channel single-ended analog multiplexer designed to connect one of sixteen inputs to a common output as determined by a 4-bit binary address. The DG407B selects one of eight differential inputs to a common differential output. Break-before-make switching action protects against momentary shorting of inputs.

An on channel conducts current equally well in both directions. In the off state each channel blocks voltages up to the power supply rails. An enable (EN) function allows the user to reset the multiplexer/demultiplexer to all switches off for stacking several devices. All control inputs, address (A_x) and enable (EN) are TTL compatible over the full specified operating temperature range.

Applications for the DG406B, DG407B include high speed data acquisition, audio signal switching and routing, ATE systems, and avionics. High performance and low power dissipation make them ideal for battery operated and remote instrumentation applications.

Designed in the 44 V silicon-gate CMOS process, the absolute maximum voltage rating is extended to 44 V, allowing operation with ± 20 V supplies. Additionally single (12 V) supply operation is allowed. An epitaxial layer prevents latchup.

FEATURES

- Low on-resistance - $R_{DS(on)}$: 45 Ω
- Low charge injection - Q: 11 pC
- Fast transition time - t_{TRANS} : 115 ns
- Low power: 0.2 mW
- Single supply capability
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details



RoHS*
Available

BENEFITS

- Higher accuracy
- Reduced glitching
- Improved data throughput
- Reduced power consumption
- Increased ruggedness
- Wide supply ranges: ± 5 V to ± 20 V

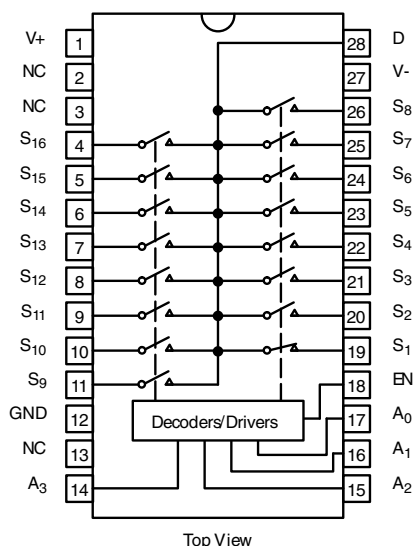
APPLICATIONS

- Data acquisition systems
- Audio signal routing
- Medical instrumentation
- ATE systems
- Battery powered systems
- High-rel systems
- Single supply systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG406B

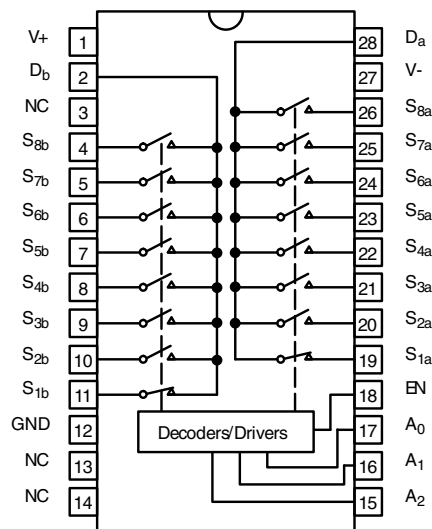
SOIC Wide-Body



Top View

DG407B

SOIC Wide-Body



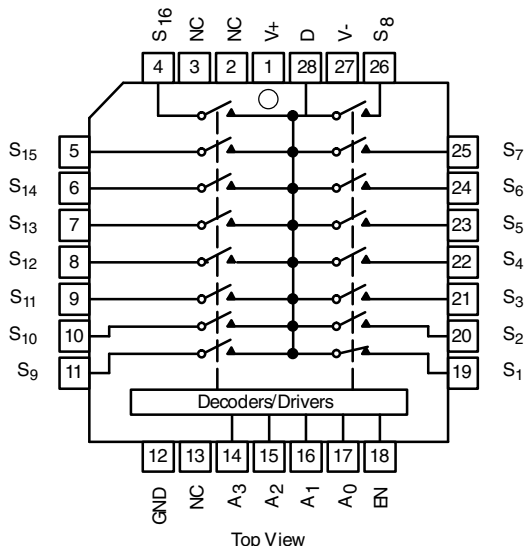
Top View



FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

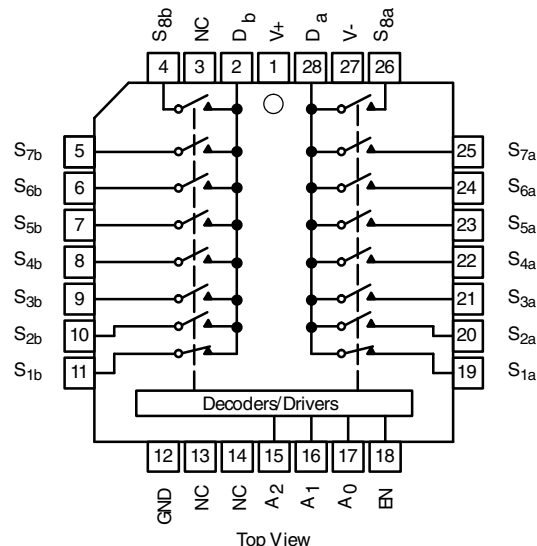
DG406B

PLCC



DG407B

PLCC



TRUTH TABLE (DG406B)

A ₃	A ₂	A ₁	A ₀	EN	ON SWITCH
X	X	X	X	0	None
0	0	0	0	1	1
0	0	0	1	1	2
0	0	1	0	1	3
0	0	1	1	1	4
0	1	0	0	1	5
0	1	0	1	1	6
0	1	1	0	1	7
0	1	1	1	1	8
1	0	0	0	1	9
1	0	0	1	1	10
1	0	1	0	1	11
1	0	1	1	1	12
1	1	0	0	1	13
1	1	0	1	1	14

TRUTH TABLE (DG406B)

1	1	1	0	1	15
1	1	1	1	1	16

TRUTH TABLE (DG407B)

A ₂	A ₁	A ₀	EN	ON SWITCH
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

Notes

- Logic "0" = $V_{AL} \leq 0.8 \text{ V}$
- Logic "1" = $V_{AH} \geq 2.4 \text{ V}$
- X = do not care

ORDERING INFORMATION (DG406B)

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +85 °C	28-pin PLCC	DG406BDN-T1-E3
	28-pin widebody SOIC	DG406BDW-E3, DG406BDW-T1-E3

ORDERING INFORMATION (DG407B)

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +85 °C	28-pin PLCC	DG407BDN-T1-E3
	28-pin widebody SOIC	DG407BDW-E3, DG407BDW-T1-E3

Note

- T1 indicates tape and reel, -E3 indicates lead (Pb)-free and RoHS-compliant, NO -E3 indicates standard tin/lead finish

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER		LIMIT	UNIT
Voltages referenced to V-	V+ to V- ^e	44	V
	GND to V-	-25	
Digital inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first	
Current (any terminal)		30	mA
Peak current, S or D (pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage temperature		-65 to +150	°C
Power dissipation (package) ^b	28-pin plastic PLCC ^c	450	mW
	28-pin widebody SOIC ^d	450	mW

Notes

- a. Signals on S_X, D_X or I_{NX} exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
b. All leads soldered or welded to PC board
c. Derate 8.3 mW/°C above 75 °C
d. Derate 6 mW/°C above 75 °C
e. Also applies when V- = GND

SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	TYP. ^c	D SUFFIX -40 °C to +85 °C		UNIT
			V ₊ = 15 V, V ₋ = -15 V			MIN. ^d	MAX. ^d	
			V _{AL} = 0.8 V, V _{AH} = 2.4 V ^f					
Analog Switch								
Analog signal range ^e		V _{ANALOG}		Full	-	-15	15	V
Drain-source on-resistance		R _{DS(on)}	V _D = ± 10 V, I _S = -10 mA sequence each switch on	Room	45	-	60	Ω
				Full	45	-	74	
R _{DS(on)} matching between channels ^g		ΔR _{DS(on)}	V _D = ± 10 V	Room	5	-	-	%
Source off leakage current		I _{S(off)}	V _S = ± 10 V, V _D = ± 10 V, V _{EN} = 0 V	Room	-	-0.5	0.5	nA
				Full	-	-5	5	
Drain off leakage current	DG406B	I _{D(off)}	V _D = ± 10 V, V _S = ± 10 V, V _{EN} = 0 V	Room	-	-1	1	
	Full			-	-40	40		
	Room			-	-1	1		
	Full			-	-20	20		
Drain on leakage current	DG406B	I _{D(on)}	V _S = V _D = ± 10 V sequence each switch on	Room	-	-1	1	
	Full			-	-40	40		
	Room			-	-1	1		
	Full			-	-20	20		
Digital Control								
Logic high input voltage		V _{INH}		Full	-	2.4	-	V
Logic low input voltage		V _{INL}		Full	-	-	0.8	
Logic high input current		I _{AH}	V _A = 2.4 V, 15 V	Full	-	-1	1	μA
Logic low input current		I _{AL}	V _{EN} = 0 V, 2.4 V, V _A = 0 V	Full	-	-1	1	
Logic input capacitance		C _{in}	f = 1 MHz	Room	6	-	-	pF



SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	TYP. ^c	D SUFFIX -40 °C to +85 °C		UNIT
		V+ = 15 V, V- = -15 V			MIN. ^d	MAX. ^d	
		V _{AL} = 0.8 V, V _{AH} = 2.4 V ^f					
Dynamic Characteristics							
Transition time	t _{TRANS}	see figure 2	Room	115	-	148	ns
			Full	-	-	161	
Break-before-make interval	t _{OPEN}	see figure 4	Room	39	10	-	
			Full	-	21	-	
Enable turn-on time	t _{ON(EN)}	see figure 3	Room	75	-	107	
			Full	-	-	123	
Enable turn-off time	t _{OFF(EN)}		Room	50	-	88	
			Full	-	-	94	
Charge injection	Q	C _L = 1 nF, V _S = 0 V, R _S = 0 Ω	Room	11	-	-	pC
Off isolation ^h	OIRR	V _{EN} = 0 V, R _L = 50 Ω, f = 1 MHz	Room	-86	-	-	dB
Source off capacitance		C _{S(off)}	Room	6	-	-	pF
Drain off capacitance	DG406B	V _{EN} = 0 V, V _D = 0 V, f = 1 MHz	Room	108	-	-	
	DG407B		Room	54	-	-	
Drain on capacitance	DG406B		Room	114	-	-	
	DG407B		Room	57	-	-	
Power Supplies							
Positive supply current	I+	V _{EN} = V _A = 0 V or 5 V	Room	23	-	30	μA
			Full	-	-	75	
Negative supply current	I-		Room	-0.02	-1	-	
			Full	-	-10	-	
Positive supply current	I+	V _{EN} = 2.4 V, V _A = 0 V	Room	28	-	500	
			Full	-	-	700	
Negative supply current	I-		Room	-0.01	-20	-	
			Full	-	-20	-	

Notes

- a. Guaranteed by ± 15 V leakage test, not production tested
- b. Room = 25 °C, full = as determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f. V_{IN} = input voltage to perform proper function
- g. ΔR_{DS(on)} = R_{DS(on)} max. - R_{DS(on)} min.
- h. Worst case isolation occurs on channel 4 due to proximity to the drain pin



SPECIFICATIONS (single supply)								
PARAMETER		SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	TYP. ^c	D SUFFIX -40 °C to +85 °C		UNIT
			V+ = 15 V, V- = -15 V			MIN. ^d	MAX. ^d	
			V _{AL} = 0.8 V, V _{AH} = 2.4 V ^f					
Analog Switch								
Analog signal range ^e		V _{ANALOG}		Full	-	0	12	V
Drain-source on-resistance		R _{DS(on)}	V _D = 3 V, I _S = -1 mA sequence each switch on	Room	78	-	100	Ω
R _{DS(on)} matching between channels ^g		ΔR _{DS(on)}		Room	5	-	-	%
Source off leakage current ^a		I _{S(off)}	V _D = 10 V or 0.5 V, V _S = 0.5 V or 10 V, V _{EN} = 0 V	Room	-	-0.5	0.5	nA
Drain off leakage current	DG406B	I _{D(off)}		Room	-	-1	1	
	DG407B			Room	-	-1	1	
Drain on leakage current	DG406B	I _{D(on)}	Room	-	-1	1		
	DG407B		Room	-	-1	1		
Dynamic Characteristics								
Transition time		t _{TRANS}	V _{S1} = 8 V, V _{S8} = 0 V, V _{IN} = 2.4 V	Room	130	-	163	ns
Enable turn-on time		t _{ON(EN)}	V _{INH} = 2.4 V, V _{INL} = 0 V, V _{IN} = 5 V	Room	93	-	125	
Enable turn-off time		t _{OFF(EN)}		Room	63	-	94	
Charge injection		Q	C _L = 1 nF, V _S = 6 V, R _S = 0 Ω	Room	9	-	-	pC
Power Supplies								
Positive supply current		I ₊	V _{EN} = 0 V or 5 V, V _A = 0 V or 5 V	Room	13	-	30	μA
				Full	-	-	75	
Positive supply current		I ₊		Room	-0.01	-20	-	
				Full	-	-20	-	

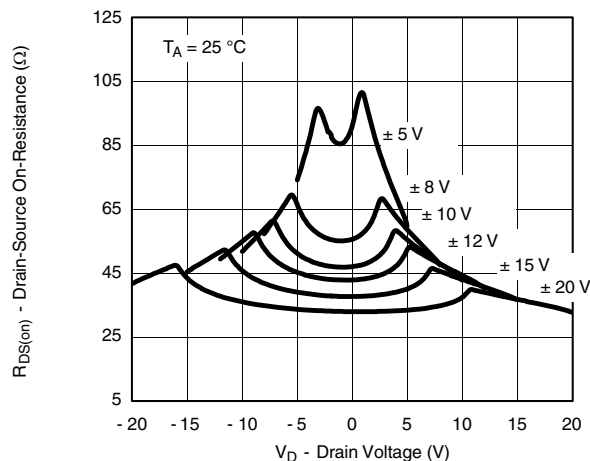
Notes

- a. Guaranteed by ± 15 V leakage test, not production tested
- b. Room = 25 °C, full = as determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f. V_{IN} = input voltage to perform proper function
- g. ΔR_{DS(on)} = R_{DS(on)} max. - R_{DS(on)} min.
- h. Worst case isolation occurs on channel 4 due to proximity to the drain pin

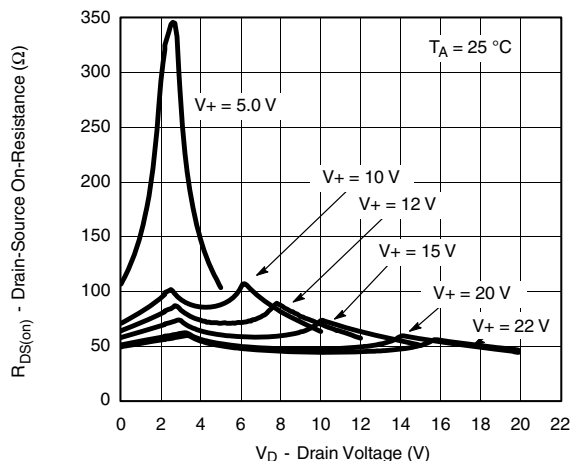
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



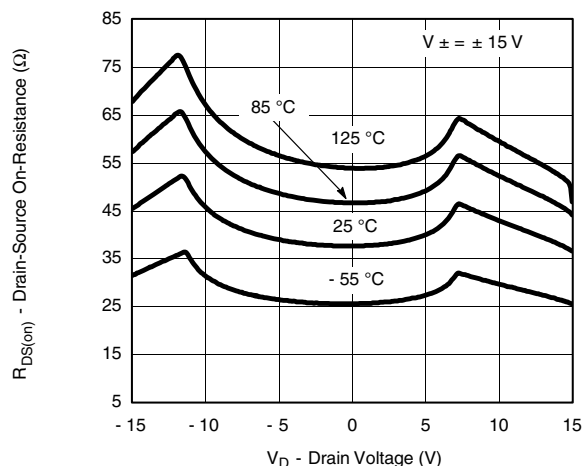
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



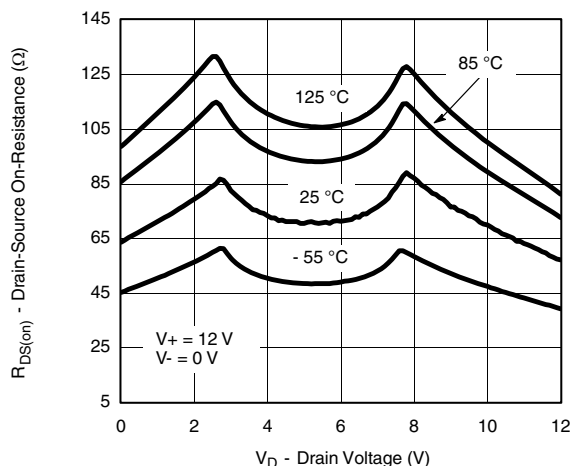
On-Resistance vs. V_D and Dual Supply Voltage



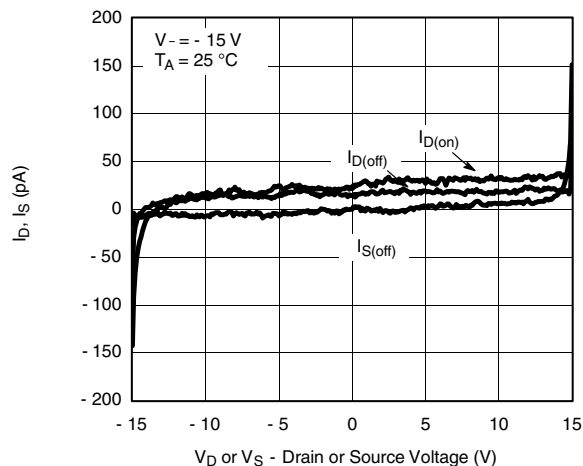
On-Resistance vs. V_D and Unipolar Supply Voltage



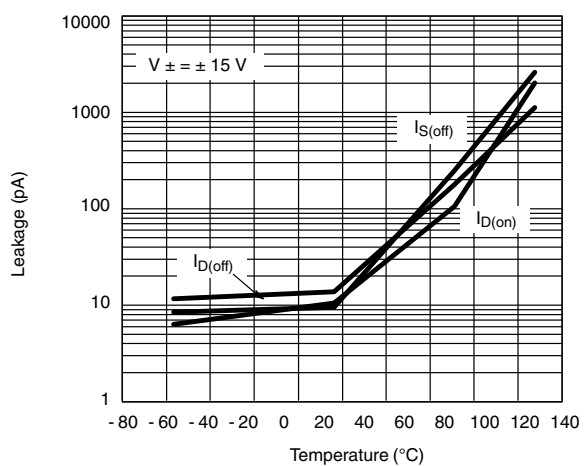
On-Resistance vs. V_D and Temperature



On-Resistance vs. V_D and Temperature



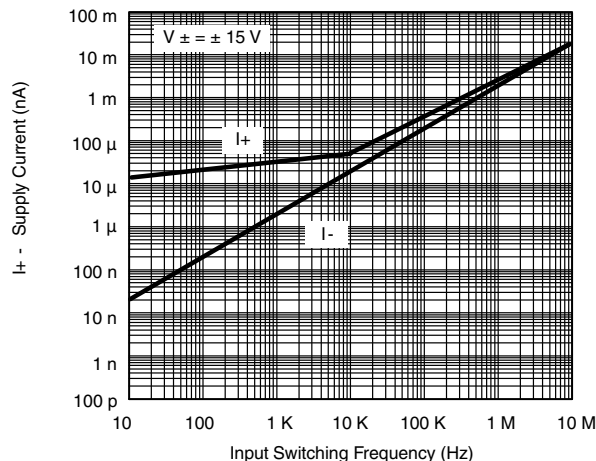
Leakage vs. Analog Voltage



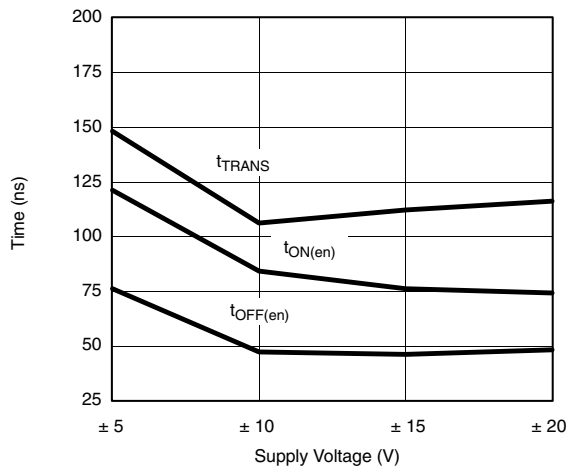
Leakage vs. Current



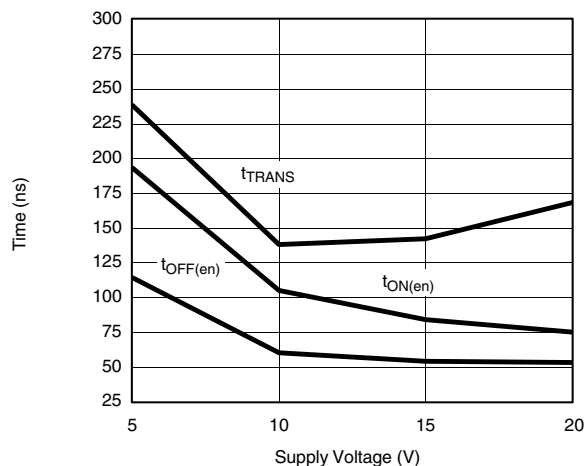
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



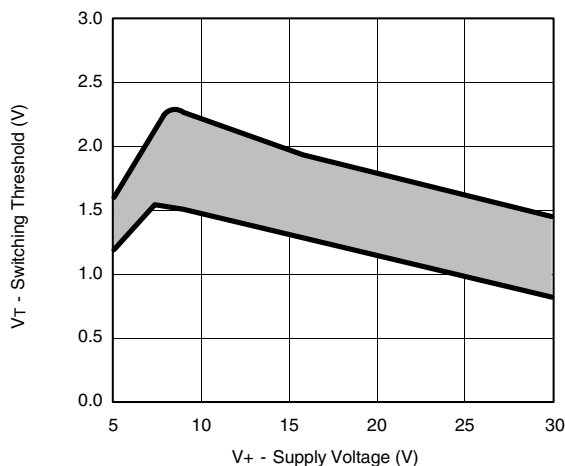
Supply Current vs. Input Switching Frequency



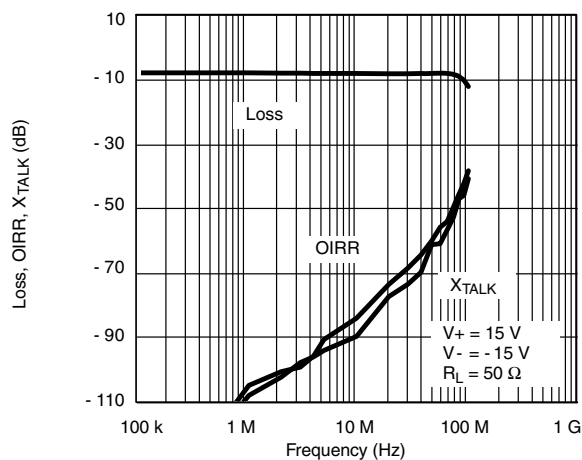
Switching Time vs. Bipolar Supplies



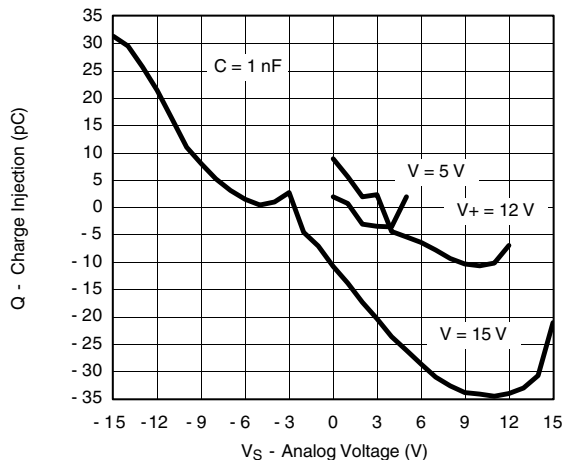
Switching Time vs. Single Supplies



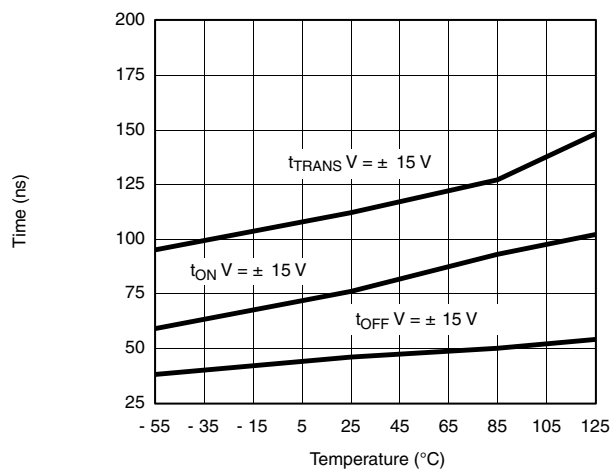
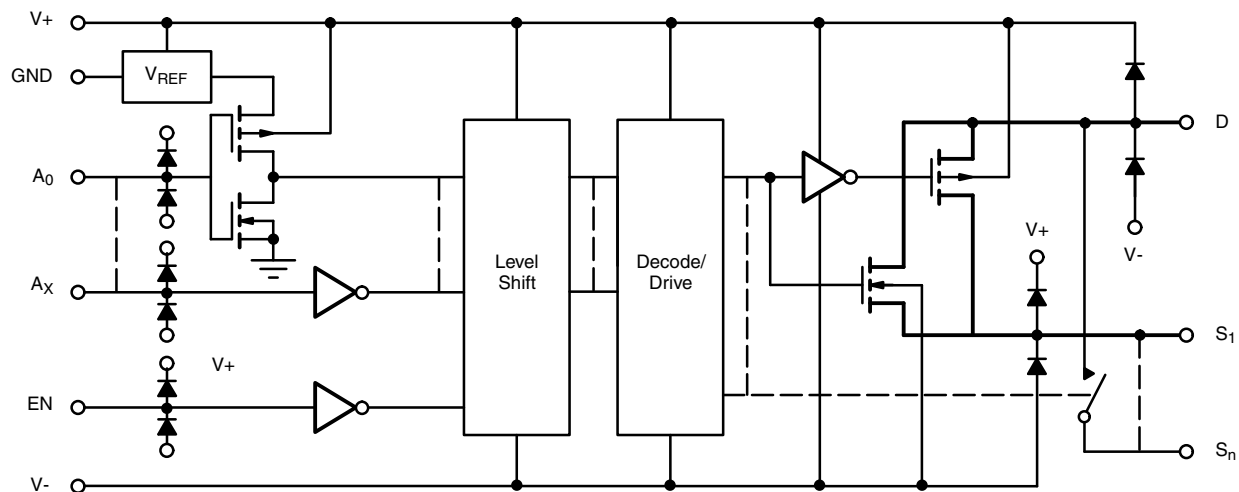
Switching Threshold vs. Supply Voltage

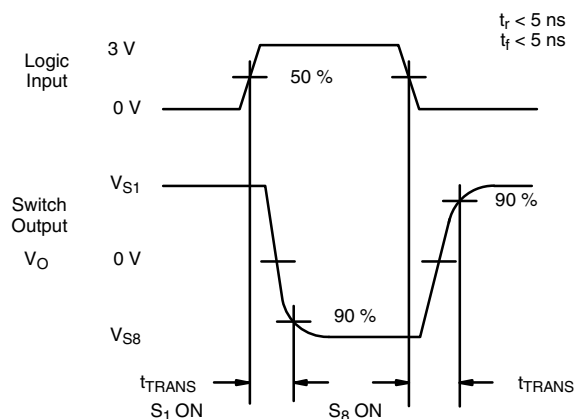
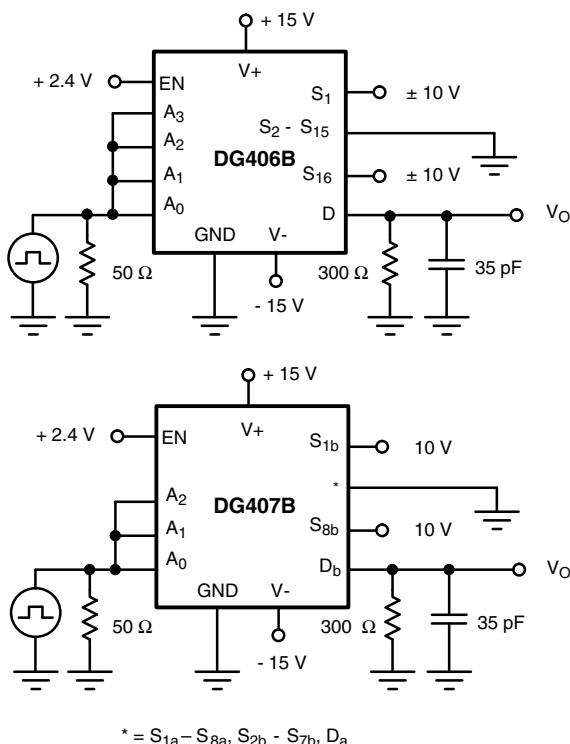
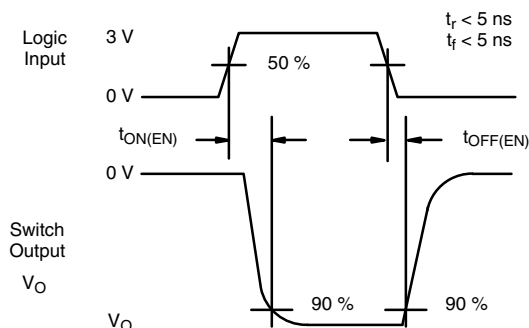
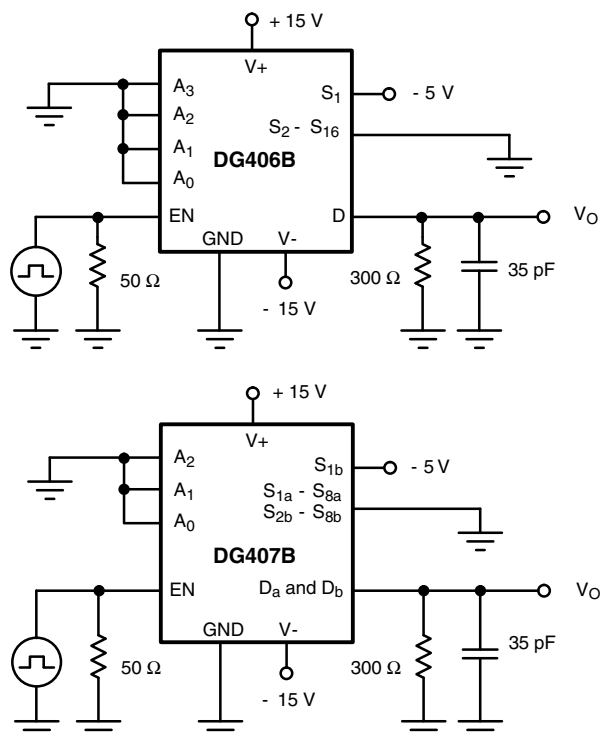


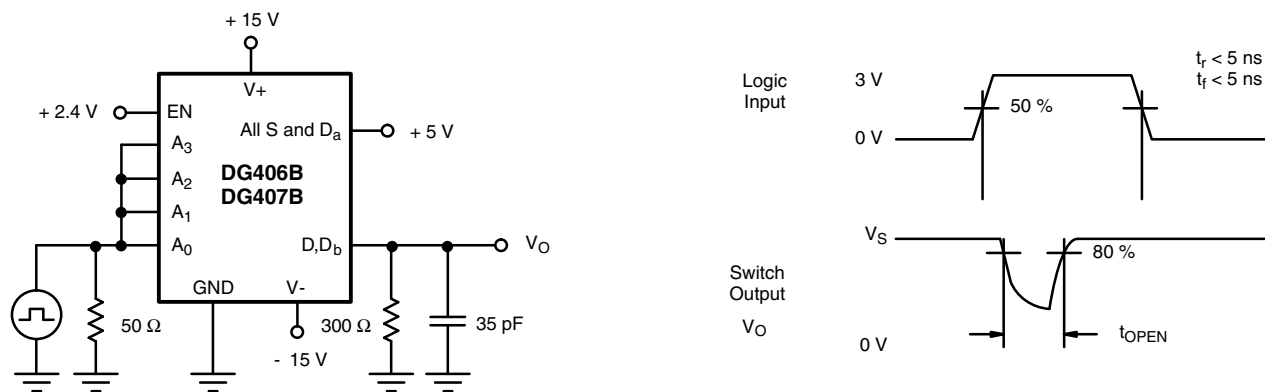
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage

TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Switching Time vs. Temperature
SCHEMATIC DIAGRAM (typical channel)

Fig. 1

TEST CIRCUITS

Fig. 2 - Transition Time

Fig. 3 - Enable Switching Time

TEST CIRCUITS

Fig. 4 - Break-Before-Make Interval

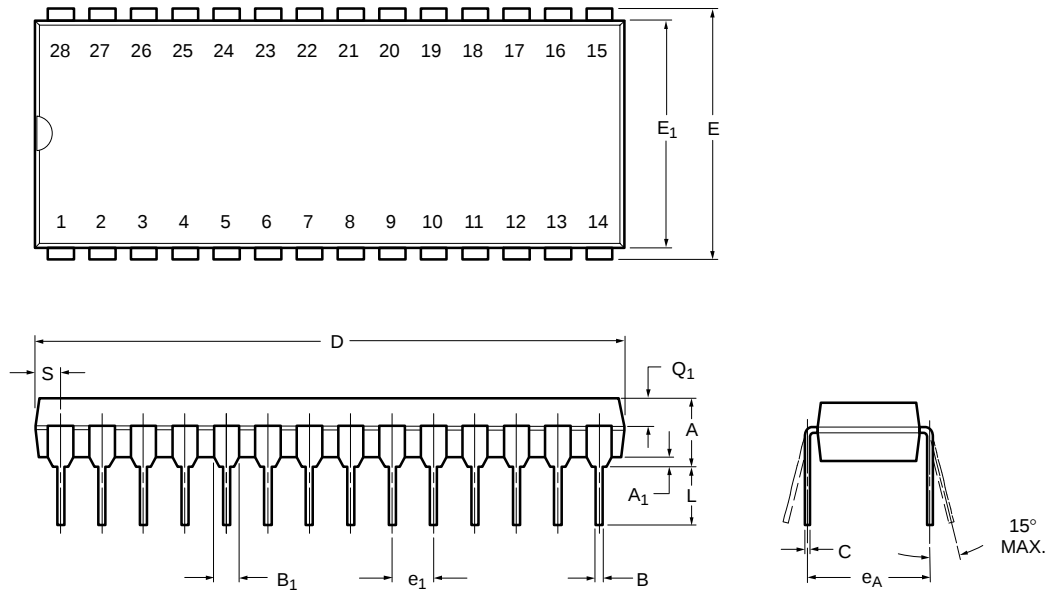
**PRODUCT SUMMARY**

Part number	DG406B	DG406B	DG407B	DG407B
Status code	2	2	2	2
Configuration	16:1 x 1	16:1 x 1	8:1 x 2	8:1 x 2
Single supply min. (V)	5	5	5	5
Single supply max. (V)	40	40	40	40
Dual supply min. (V)	5	5	5	5
Dual supply max. (V)	20	20	20	20
On-resistance (Ω)	45	45	45	45
Charge injection (pC)	11	11	11	11
Source on capacitance (pF)	114	114	57	57
Source off capacitance (pF)	6	6	6	6
Leakage switch on typ. (nA)	-	-	-	-
Leakage switch off max. (nA)	0.5	0.5	0.5	0.5
-3 dB bandwidth (MHz)	-	-	-	-
Package	PLCC-28	SO-28 (wide)	PLCC-28	SO-28 (wide)
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare
Interface	Parallel	Parallel	Parallel	Parallel
Single supply operation	Yes	Yes	Yes	Yes
Dual supply operation	Yes	Yes	Yes	Yes
Turn on time max. (ns)	148	148	148	148
Crosstalk and off isolation	-86	-86	-86	-86

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72552.



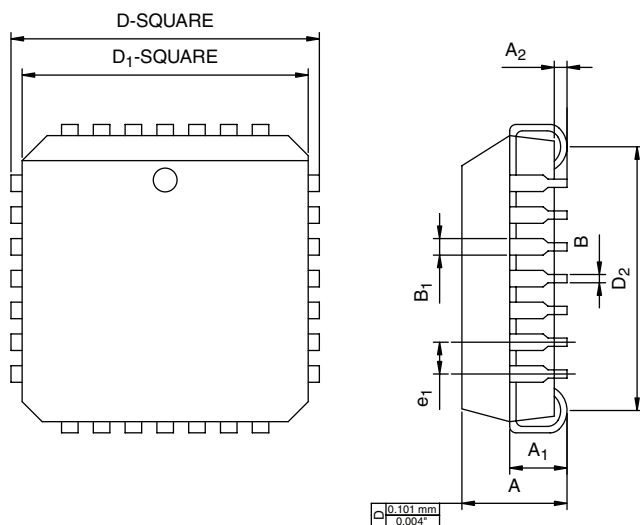
PDIP: 28-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	2.29	5.08	0.090	0.200
A₁	0.39	1.77	0.015	0.070
B	0.38	0.56	0.015	0.022
B₁	0.89	1.65	0.035	0.065
C	0.204	0.30	0.008	0.012
D	35.10	39.70	1.380	1.565
E	15.24	15.88	0.600	0.625
E₁	13.21	14.73	0.520	0.580
e₁	2.29	2.79	0.090	0.110
e_A	14.99	15.49	0.590	0.610
L	2.60	5.08	0.100	0.200
Q₁	0.95	2.345	0.0375	0.0925
S	0.995	2.665	0.0375	0.105

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5488

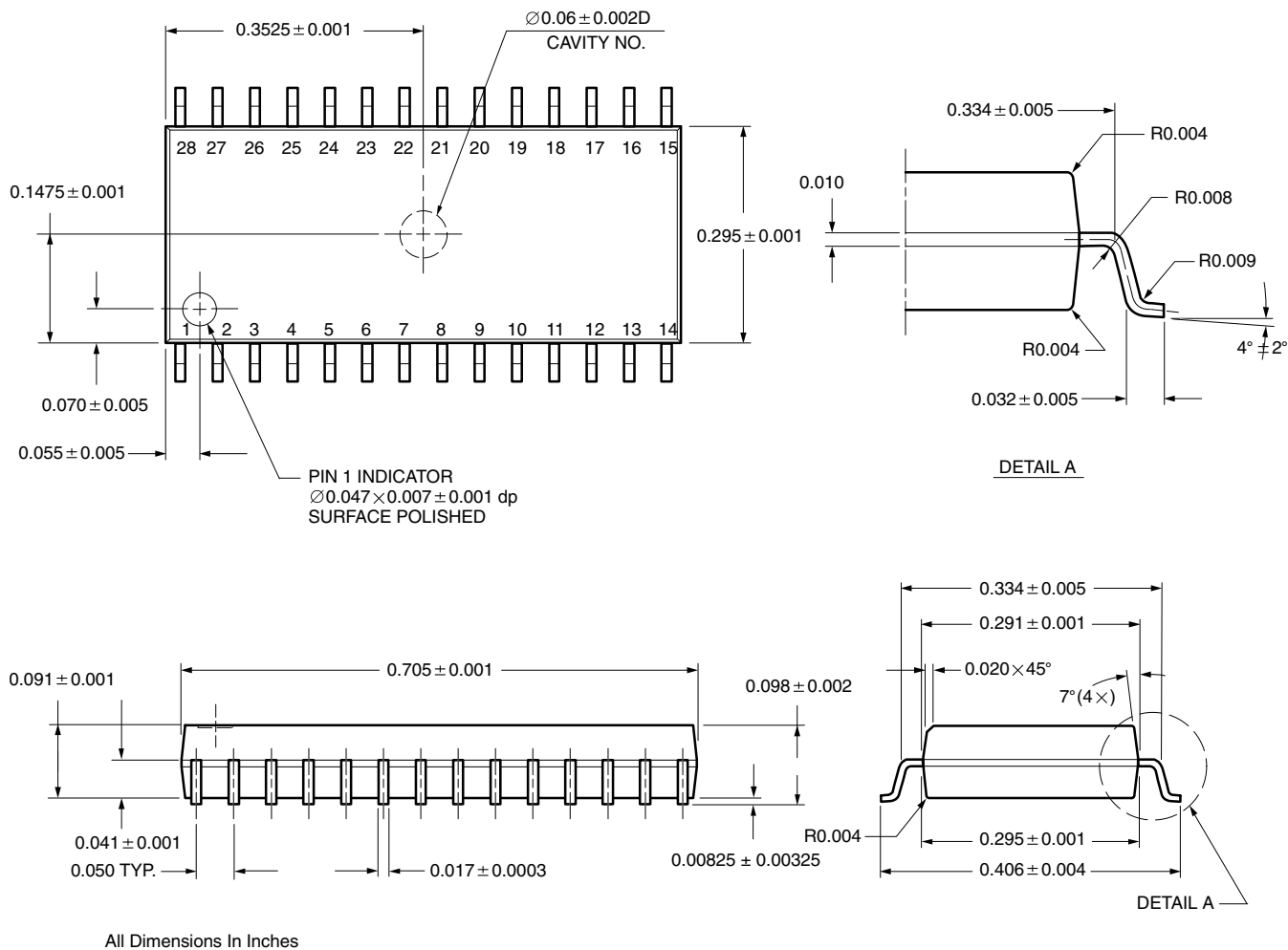
PLCC: 28-LEAD



DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.20	4.57	0.165	0.180
A ₁	2.29	3.04	0.090	0.120
A ₂	0.51	-	0.020	-
B	0.331	0.553	0.013	0.021
B ₁	0.661	0.812	0.026	0.032
D	12.32	12.57	0.485	0.495
D ₁	11.430	11.582	0.450	0.456
D ₂	9.91	10.92	0.390	0.430
e ₁	1.27 BSC		0.050 BSC	
ECN: T09-0766-Rev. D, 28-Sep-09 DWG: 5491				



SOIC (WIDE-BODY): 28-LEADS



ECN: E11-2209-Rev. D, 01-Aug-11
DWG: 5850



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.